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APPLICATION NO.	FILING	G DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/044,271	01/10/2002		Ga Lane Chen		7843	
25859	7590	03/23/2005		EXAMINER		
WEI TE CHUNG				STEIN, STEPHEN J		
FOXCONN	INTERNATI	ONAL, INC.	•			
1650 MEMOREX DRIVE				ART UNIT	PAPER NUMBER	
SANTA CL	ARA, CA 9	5050		1775		
				DATE MAIL CD. 02/22/200	•	

Please find below and/or attached an Office communication concerning this application or proceeding.

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. ,	Application No.	Applicant(s)	<u> </u>
	10/044,271	CHEN ET AL.	
Office Action Summary	Examiner	Art Unit	
	Stephen J Stein	1775	
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the	correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period of the period of the period for reply within the set or extended period for reply will, by statute any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be t y within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS fron , cause the application to become ABANDON	imely filed ys will be considered timely. in the mailing date of this communication. ED (35 U.S.C. § 133)	
Status			
Responsive to communication(s) filed on <u>03 Ja</u> This action is FINAL . 2b)⊠ This Since this application is in condition for allowal closed in accordance with the practice under E	action is non-final. nce except for formal matters, p		
Disposition of Claims			
4) ⊠ Claim(s) <u>1-18</u> is/are pending in the application 4a) Of the above claim(s) <u>16-18</u> is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>1-3,5,6 and 8-15</u> is/are rejected. 7) ⊠ Claim(s) <u>4,6 and 7</u> is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o	vn from consideration.		
Application Papers			
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	epted or b) objected to by the drawing(s) be held in abeyance. So tion is required if the drawing(s) is o	ee 37 CFR 1.85(a). bjected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applica rity documents have been receiv u (PCT Rule 17.2(a)).	tion No ved in this National Stage	
Attachment(s) 1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summar	v (PTO 412)	
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail [,
S. Patent and Trademark Office		*****	

Part of Paper No./Mail Date 20050316

Application/Control Number: 10/044,271 Page 2

Art Unit: 1775

DETAILED ACTION

Election/Restrictions

1. Applicant's election of Group I, claims 1-15 in the reply filed on January 3, 2005 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

Claim Rejections - 35 USC § 112

- 2. The following is a quotation of the second paragraph of 35 U.S.C. 112:
 - The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 3. Claims 5 and 9 and is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.
- 4. Claim 5 recites the limitation "...- Y_2O_3 system wherein Y can be aluminum (Al).". This limitation makes the claim unclear to the examiner because it is unclear if the " Y_2O_3 " can refers to yttria. If not, the examiner suggests using another variable to eliminate ambiguity in the claim.
- 5. Claim 9 recites the limitation "silicate dioxide". This is unclear to the examiner. Does applicant mean to recite the limitation "silica dioxide"?

Claim Rejections - 35 USC § 102

6. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an

Application/Control Number: 10/044,271

Art Unit: 1775

international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Page 3

7. Claims 1-3, 9-11, 14 and 15 are rejected under 35 U.S.C. 102(e) as being anticipated by US 6,798,553 (Scobey et al.).

Scobey teaches an optical filter manufactured by providing a substrate wafer of glass, indium phosphide, silica or a silicon wafer (col. 6, lines 21-23), polishing the substrate wafer (col. 14, lines 53-59), then either magnetron or ion beam sputtering (higher than room temperature coating technique) a film stack on the substrate (col. 15, lines 1-3). The reference further teaches that the wedge coating (film stack) can include layers of Ta₂O₅ and SiO₂ (col. 9, lines 32-38). Scobey finally teaches that the coated substrate may later be cut or diced to form smaller fragments known as coupon which may still further diced into one more static optically coupled etalons (col. 20, lines 44-49). With regard to the claimed substrate CTE, transparency of the substrate, and coating endurance to tensile and compressive stress, it is expected that the disclosed laminate would exhibit these properties since the materials are the same as disclosed by applicant.

Claim Rejections - 35 USC § 103

- 8. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 9. Claim 8 is rejected under 35 U.S.C. 103(a) as being unpatentable over Scobey as applied to claim 1 above.

Art Unit: 1775

Although Scobey fails to teach the claimed average roughness of the substrate after poslishing, absent a showing of criticality with respect to the claimed roughness it would have been obvious to a person of ordinary skill in the art at time of the invention to optimize the polished surface roughness (a result effective variable) through routine experimentation. It has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

10. Claims 12 and 13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Scobey in view of US 4,793,908 (Scott et al.).

As stated above, Scobey teaches an optical filter comprising manufactured by providing a substrate wafer, and forming a film stack on the substrate by ion beam sputtering (heated ion beam source with electrical filed acceleration), and dicing the film coated wafer into smaller pieces. Scobey does not specifically teach that the ion beam source is a Kaufman type source and fails to teach the mean energy of the accelerated ions is within the range of 100 to 1500 eVolts.

Scott teaches a method of making an optical stacked antireflective film on a substrate by ion beam sputtering using a Kaufman type ion beam source (col. 6, lines 53-68) and further teaches that electrons are accelerated from the cathode to the anode and have energy of 500-1500 volts (col. 7, lines 10-18). The reference further teaches that Kaufman ion beam source along with the magnets, cause electrons to be accelerated from cathode to the anode and to spiral, and that this spiral motion effectively increases the distance which the electrons travel in reaching any anode surface and thereby increases the probability of an atom ionization through electron collision (col. 7, lines 1-10).

Application/Control Number: 10/044,271

Page 5

Art Unit: 1775

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of the invention to use the Kaufman ion beam source at 500 – 1500 volts energy as taught by Scott for the sputtering method disclosed by Scobey because it would provide increased probability of atom ionization at the target surface and therefore provide a more efficient coating process.

Allowable Subject Matter

- 11. Claim 5 would be allowable if rewritten to overcome the rejection(s) under 35 U.S.C. 112, 2nd paragraph, set forth in this Office action and to include all of the limitations of the base claim and any intervening claims.
- 12. Claims 4, 6 and 7 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 13. The following is a statement of reasons for the indication of allowable subject matter:

 The prior art of record fails to teach or suggest the claimed glass substrate compositions claimed in dependent claims 4-7.

Conclusion

14. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Stephen Stein whose telephone number is 572-272-1544. The examiner can normally be reached on Monday through Friday from 8:30 a.m. to 5:00 p.m. If the attempts to reach the examiner are unsuccessful, the examiner's supervisor, Deborah Jones can be reached by dialing 571-272-1535. The official fax number is 703-872-9306.

Art Unit: 1775

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

March 16, 2005

Stephen J. Stein Primary Examiner

Art Unit 1775